



Low voltage fast-switching PNP power transistor

Preliminary Data

General features

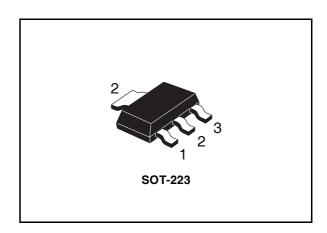
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Surface mounting device in medium power SOT-223 package
- In compliance with the 2002/93/EC European Directive



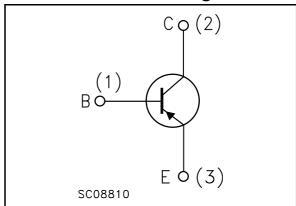
The device is manufactured in PNP planar technology by using a "Base Island" layout. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

Applications

- Emergency lighting
- Voltage regulators
- Relay drivers
- High efficiency low voltage switching applications



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing	
STN951	N951	SOT-223	Tape & reel	

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STN951 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-60	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-60	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-6	V
I _C	Collector current	-5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-10	Α
I _B	Base current	-1	Α
I _{BM}	Base peak current (t _P < 5ms)	-2	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
T _j	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb} ⁽¹⁾	Thermal resistance junction-amb max	78	°C/W

(1) Device mounted on PCB area of $1\,\mathrm{cm}^2$

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Electrical characteristics STN951

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditio	ns Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -60V			-0.1	μА
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5V			-0.1	μΑ
V _{(BR)CBO} (2)	Collector-base Breakdown voltage (I _E =0)	I _C = -100μA	-60			٧
V _{(BR)CEO} (2)	Collector-emitter Breakdown voltage (I _B =0)	I _C = -10mA	-60			٧
V _{(BR)EBO} (2)	Collector-base Breakdown voltage (I _C =0)	I _E = -100μA	-6			٧
		$I_C = -100 \text{mA}$ $I_B = -5$	5mA	-10	-50	mV
V _{CE(sat)} (2)	Collector-emitter	$I_C = -1A$ $I_B = -1$		-70	-120	mV
, ,	saturation voltage	$I_C = -2A$ $I_B = -$	50mA	-140	-250	mV
		$I_C = -5A$ $I_B = -6$	200mA	-350	-500	mV
V _{BE(sat)} (2)	Base-emitter saturation voltage	$I_C = -4A$ $I_B = -4$	200mA	-1	-1.15	V
V _{BE(on)} (2)	Base-emitter on voltage	$I_C = -4A$ $V_{CE} = -4A$	= -1V	-0.89	-1	V
		$I_C = -10 \text{mA}$ $V_{CE} = -10 \text{mA}$	= -1V 150	300		
ı. (2)	DC current gain	$I_C = -2A$ V_{CE}	= -1V 150	270	350	
h _{FE} ⁽²⁾		$I_C = -5A$ V_{CE}	= -1V 65	90		
		$I_C = -10A$ V_{CE}	= -1V 10	25		
f _T	Transition frequency	V _{CE} = -10V I _C = -	-100mA	130		MHz
C _{CBO}	Collector-base capacitance	V _{CB} = -10V f =	1MHz	60		pF
	Resistive load			80		ns
t _{on}	Turn-on time	$I_C = -1A$ V_{CC}	c = -30V	600		ns
t _s	Storage time	$I_{B1} = -I_{B2} = -0.1A$		70		ns
t _f	Fall time			, ,		110

Note (2) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

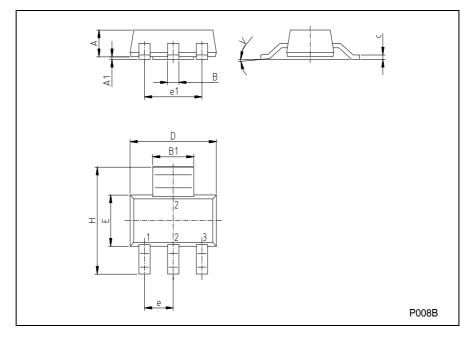
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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SOT-223 MECHANICAL DATA

DIM.	mm			inch		
Dim.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			1.80			0.071
В	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
С	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.30			0.090	
e1		4.60			0.181	
Е	3.30	3.50	3.70	0.130	0.138	0.146
Н	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



STN951 Revision history

4 Revision history

Table 4. Revision history

Date	Revision	Changes	
03-Oct-2006	1	Initial release.	
30-Nov-2006	2	The emitter base voltage value has been modified	

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